

IPB114N03L G

IPB114N03L G Information

Part N Manufa Catego Descrip Packag	acturer Infineon Technologies ry Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single otion MOSFET N-CH 30V 30A TO263-3	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPB114N03L G Specifications

Manufacturer Part Number	IPB114N03L G	
Manufacturer	Infineon Technologies	
Category	Discrete Semiconductor Products	
	Transistors - FETs, MOSFETs - Single	
Package	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB	
Series	OptiMOS?	
FET Type	N-Channel	
Technology	MOSFET (Metal Oxide)	
Drain to Source Voltage (Vdss)	30V	
Current - Continuous Drain (Id) @ 25°C	30A (Tc)	
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V	
Vgs(th) (Max) @ Id	2.2V @ 250µA	
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds	1500pF @ 15V	
Vgs (Max)	$\pm 20 V$	
FET Feature	-	
Power Dissipation (Max)	38W (Tc)	
Rds On (Max) @ Id, Vgs	11.4 mOhm @ 30A, 10V	
Operating Temperature	-55°C ~ 175°C (TJ)	
Mounting Type	Surface Mount	
Supplier Device Package	PG-TO263-2	
Package / Case	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB	
	Report errors?	

IPB114N03L G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE SUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPB114N03L G Payment Methods



IPB114N03L G Shipping Methods



If you have any question about IPB114N03L G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com